High Speed Switching Silicon N-channel MOSFET

AEC-Q101 Compliance

## **DESCRIPTION**

INK021ABS1 is a Silicon N-channel MOSFET.

This product is most suitable for use such as portable machinery, because voltage drive and low on resistance.

## **FEATURE**

- •Input impedance is high, and not necessary to consider a drive electric current.
- High drain current. I<sub>D</sub>=1.4A
- •Drive voltage 4.0V
- •Low on Resistance. RDS(on)=0.2  $\Omega$  (TYP)
- •High power Dissipation. PD=600mW

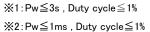
## **APPLICATION**

Switching

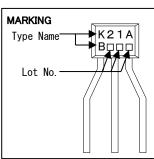
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# MAXIMUM RATINGS (Ta=25°C)

Parameter	Symbol	Rating	Unit	
Drain-Source Voltage	VDSS	100	V	
Gate-Source Voltage	Vgss	±20	V	
Drain Current(DC)	<b>I</b> D	1.4	Α	
Drain Current(Pulse)	<b>I</b> DР	2(※1)	Α	
		8(※2)		
Total Power Dissipation	PD	600	mW	
Channel Temperature	Tch	+150	°C	
Storage Temperature	Tstg	−55 <b>~</b> +150	°C	



# G S S

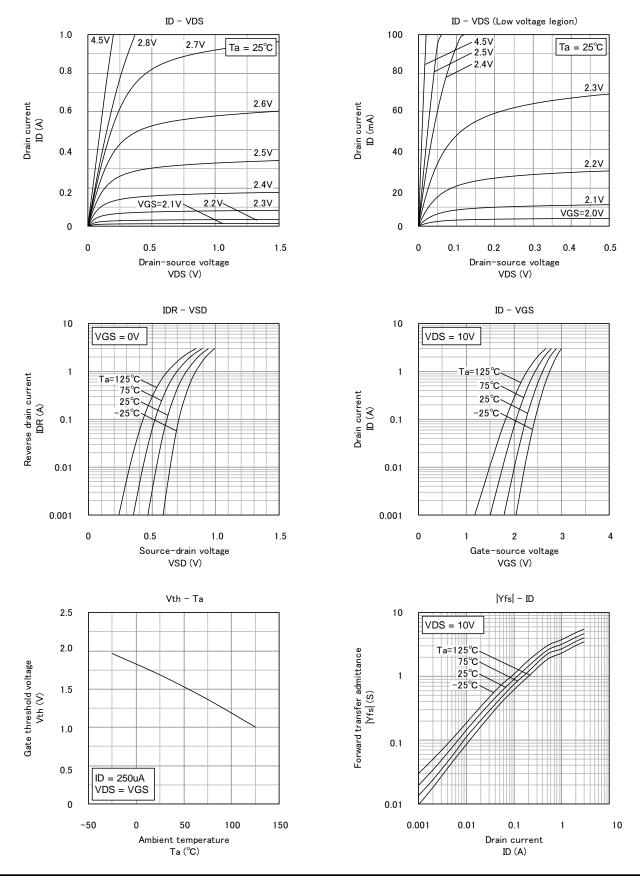


# ELECTRICAL CHARACTERISTICS (Ta=25°C)

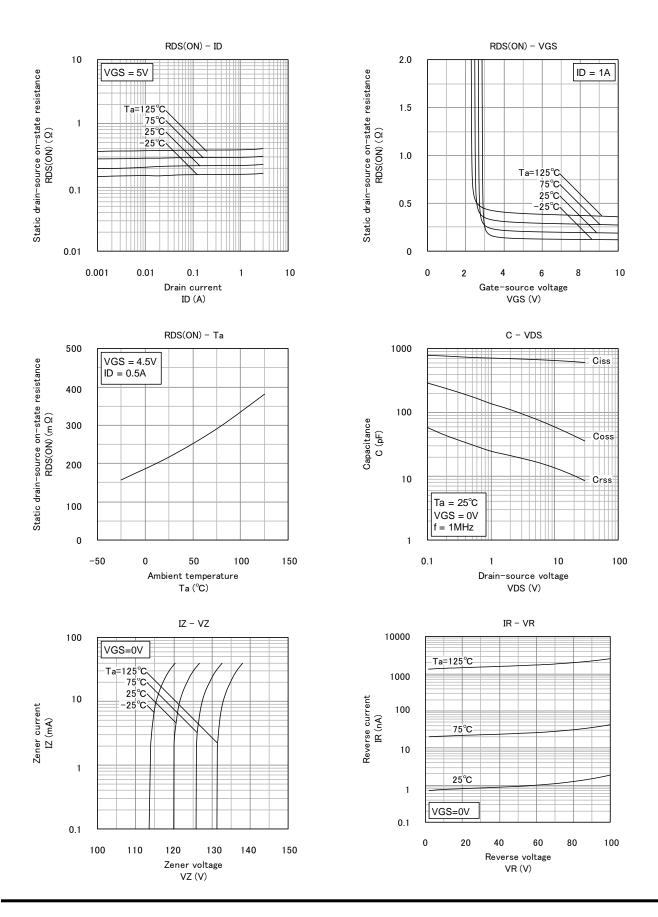
Parameter	Symbol	Test Condition	Limit			Unit
			MIN	TYP	MAX	Offic
Drain-Source Breakdown Voltage	V(BR)DSS	$I_D=100 \mu A, V_{GS}=0V$	100	_	_	٧
Gate-Source Leak current	Igss	V <sub>GS</sub> =±20V, V <sub>DS</sub> =0V	-	-	±10	μΑ
Zero Gate Voltage Drain Current	IDSS	V <sub>DS</sub> =100V ,V <sub>GS</sub> =0V	-	-	1.0	μΑ
Gate Threshold Voltage	Vth	I $_{D}$ =250 $\mu$ A, V $_{DS}$ = V $_{GS}$	1.0	-	2.5	٧
Forward Transfer Admittance	Yfs	V <sub>DS</sub> =10V, I <sub>D</sub> =1A	-	3.6	-	S
Static Drain-Source On-State Resistance	RDS(ON)	I <sub>D</sub> =1A, V <sub>GS</sub> =4.5V	-	0.2	0.35	Ω
Input Capacitance	Ciss	\/ -10\/ \/ -0\/ (-1MI)	-	660	_	pF
Output Capacitance	Coss	V <sub>DS</sub> =10V, V <sub>GS</sub> =0V,f=1MHz	-	80	-	
Switching Time	ton	V <sub>DD</sub> =30V , I <sub>D</sub> =1A	-	580	-	ns
	toff	V <sub>GS</sub> =0∼5V	_	910	_	

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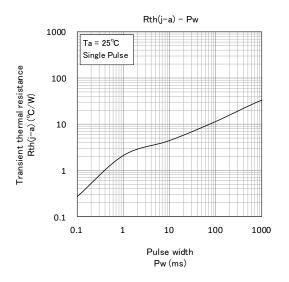
# TYPICAL CHARACTERISTICS

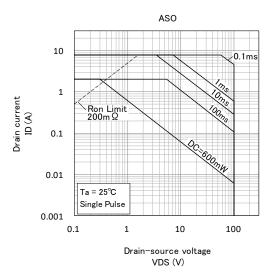


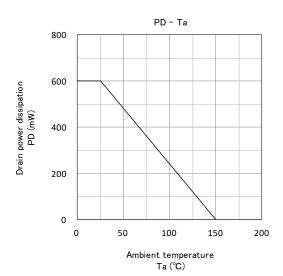
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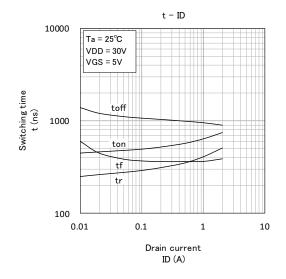


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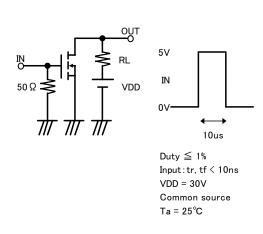


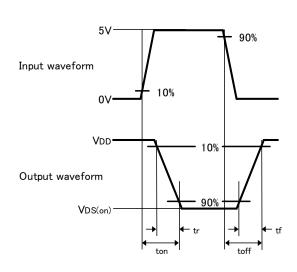






# Switching time test condition





### Keep safety first in your circuit designs!

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